

**Supporting Information for:**

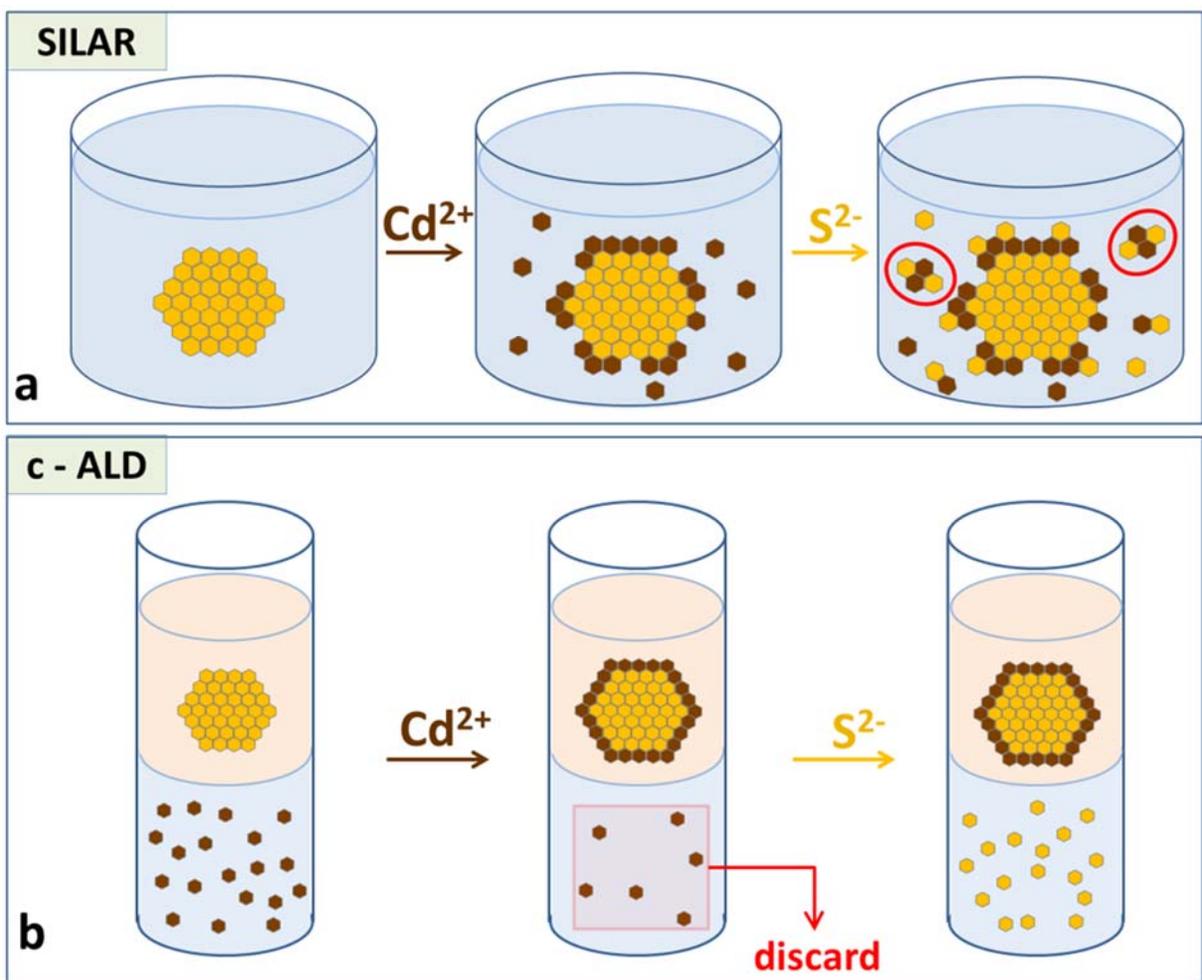
Colloidal Synthesis of Monodisperse  
Semiconductor Nanocrystals through Saturated Ionic  
Layer Adsorption.

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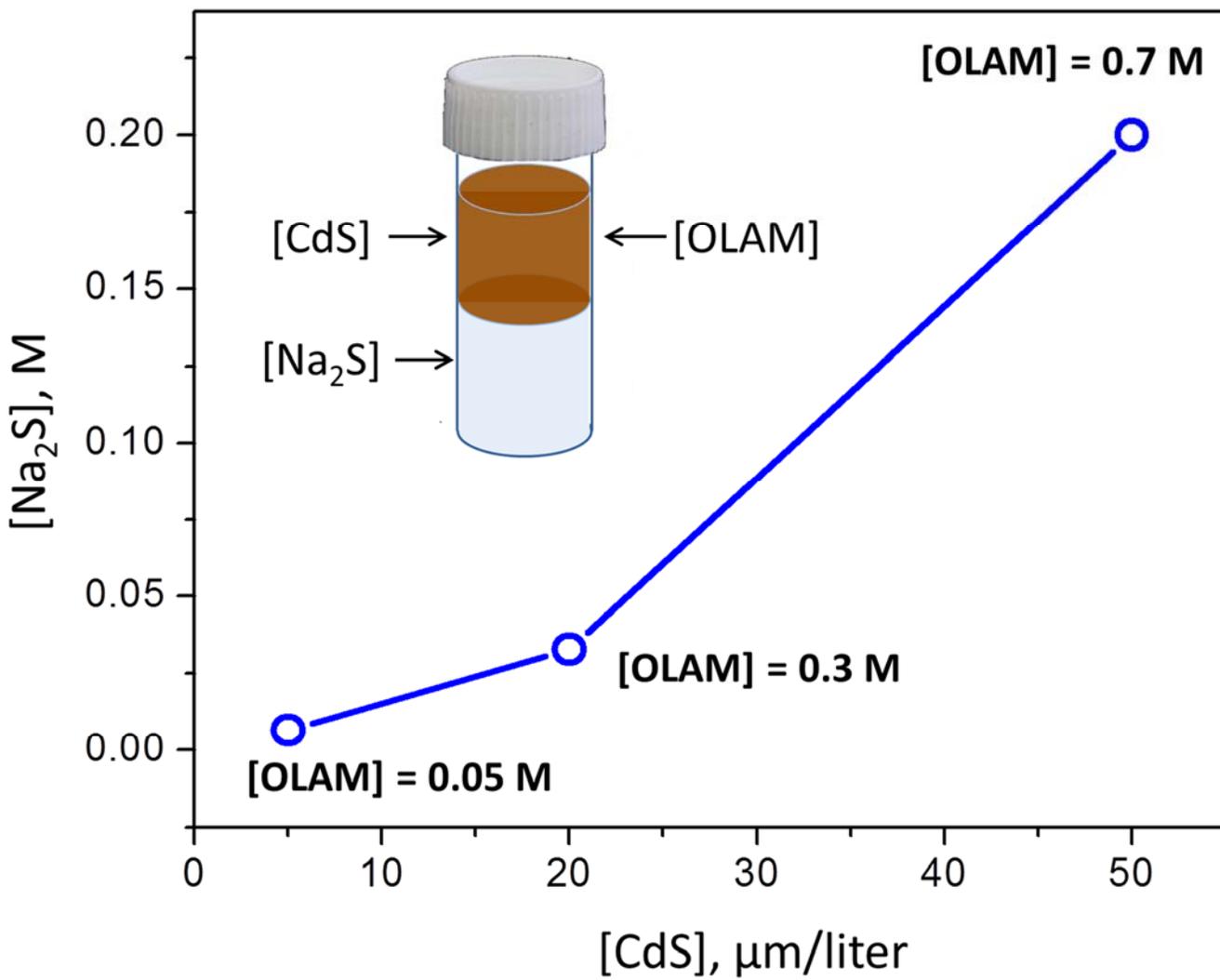
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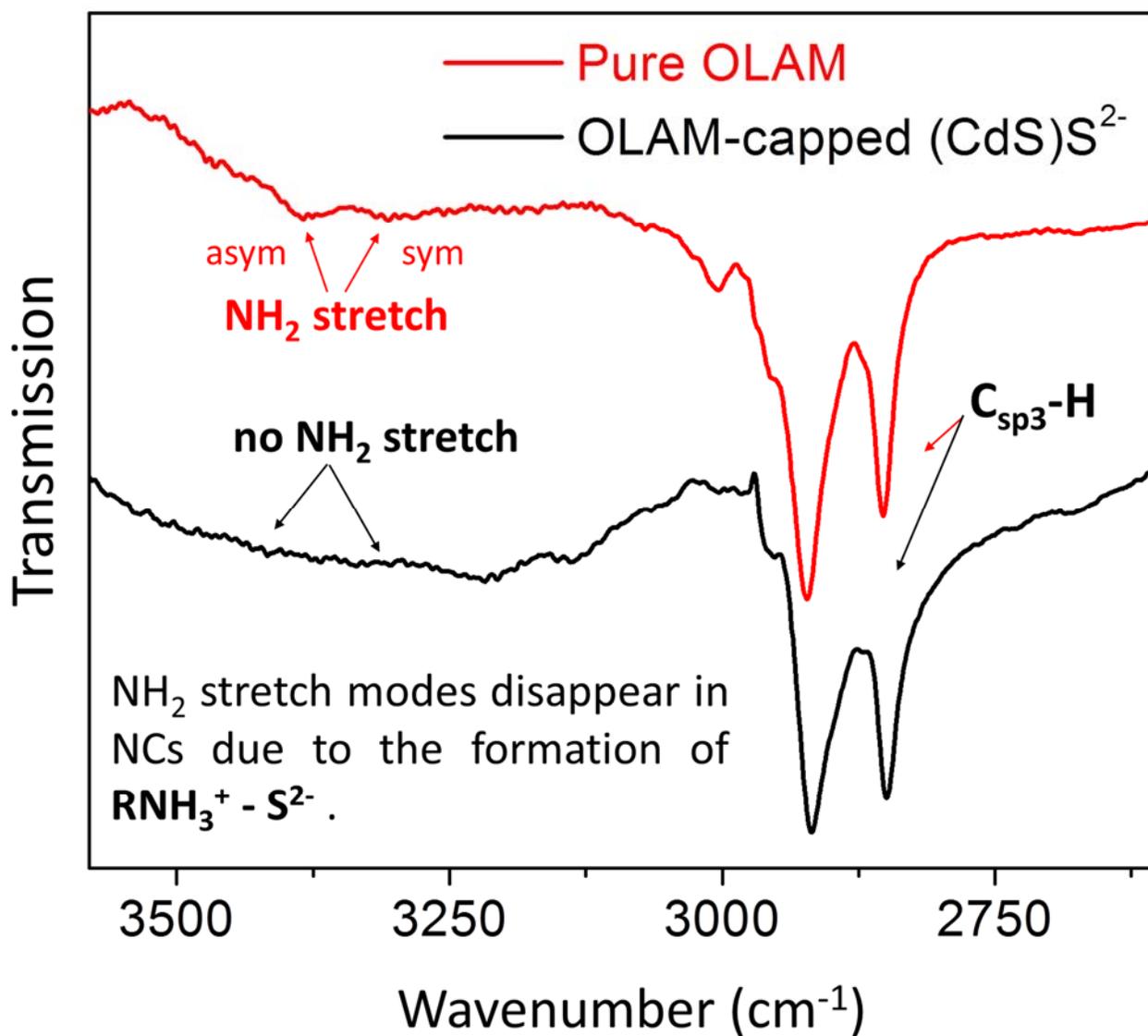


**Figure SF1.** A schematic illustration of the key differences between SILAR and c-ALD techniques for the nanocrystal shell growth. (a). The SILAR synthesis is performed in a single-phase reaction mixture, which results in the accumulation of unreacted precursors causing the secondary nucleation (at high precursor concentrations) or sub-monolayer growth (at low precursor concentrations). (b). The c-ALD employs a two-phase growth mixture, which is designed to separate precursors from nanoparticles. As a result, unreacted precursors can be removed after the half-monolayer (cationic or anionic) is grown.

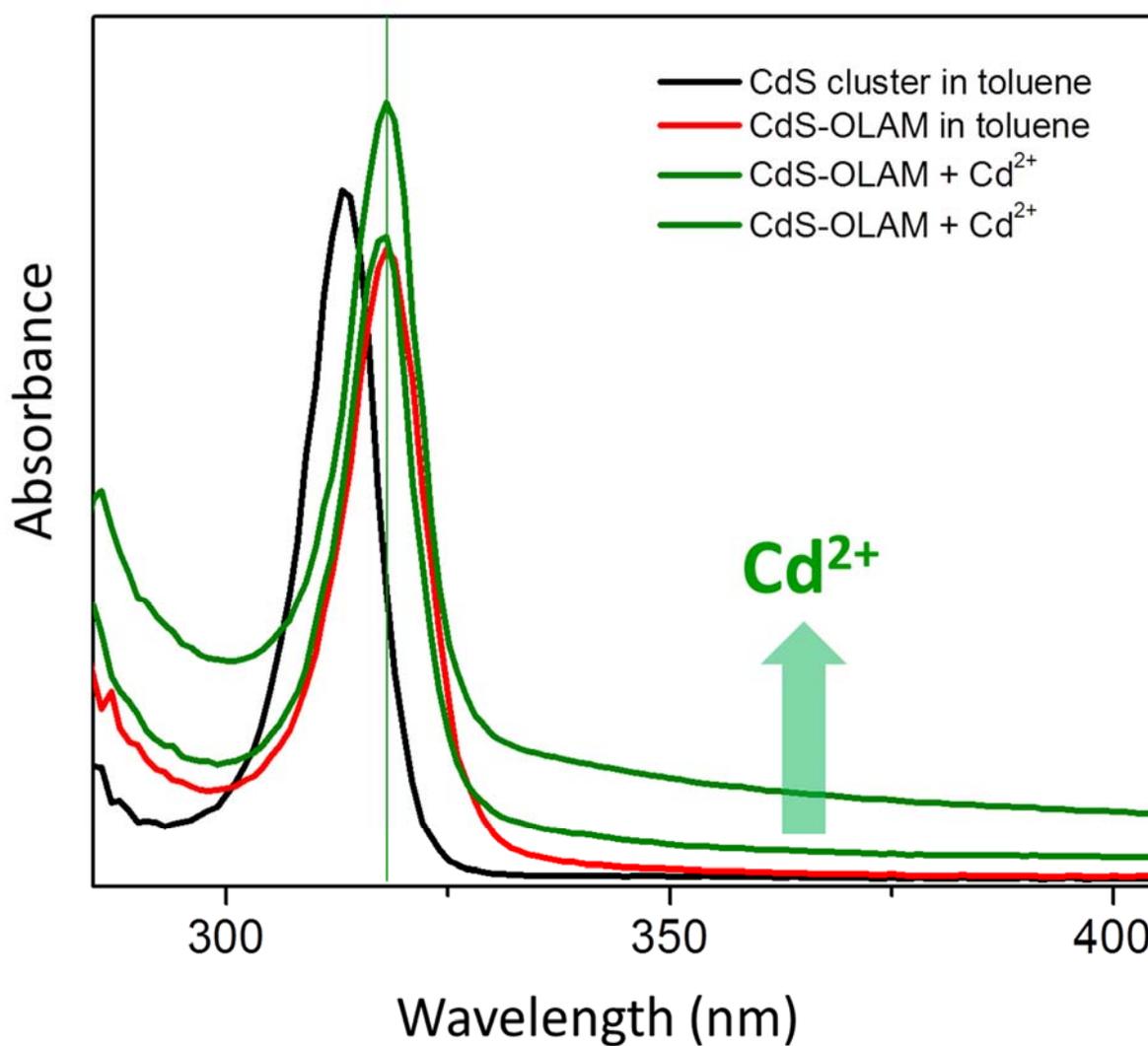


**Figure SF2.** The relationship between the minimal concentration of the Na<sub>2</sub>S precursor in the formamide layer (needed for a saturated half-monolayer growth) and the concentration of CdS seeds

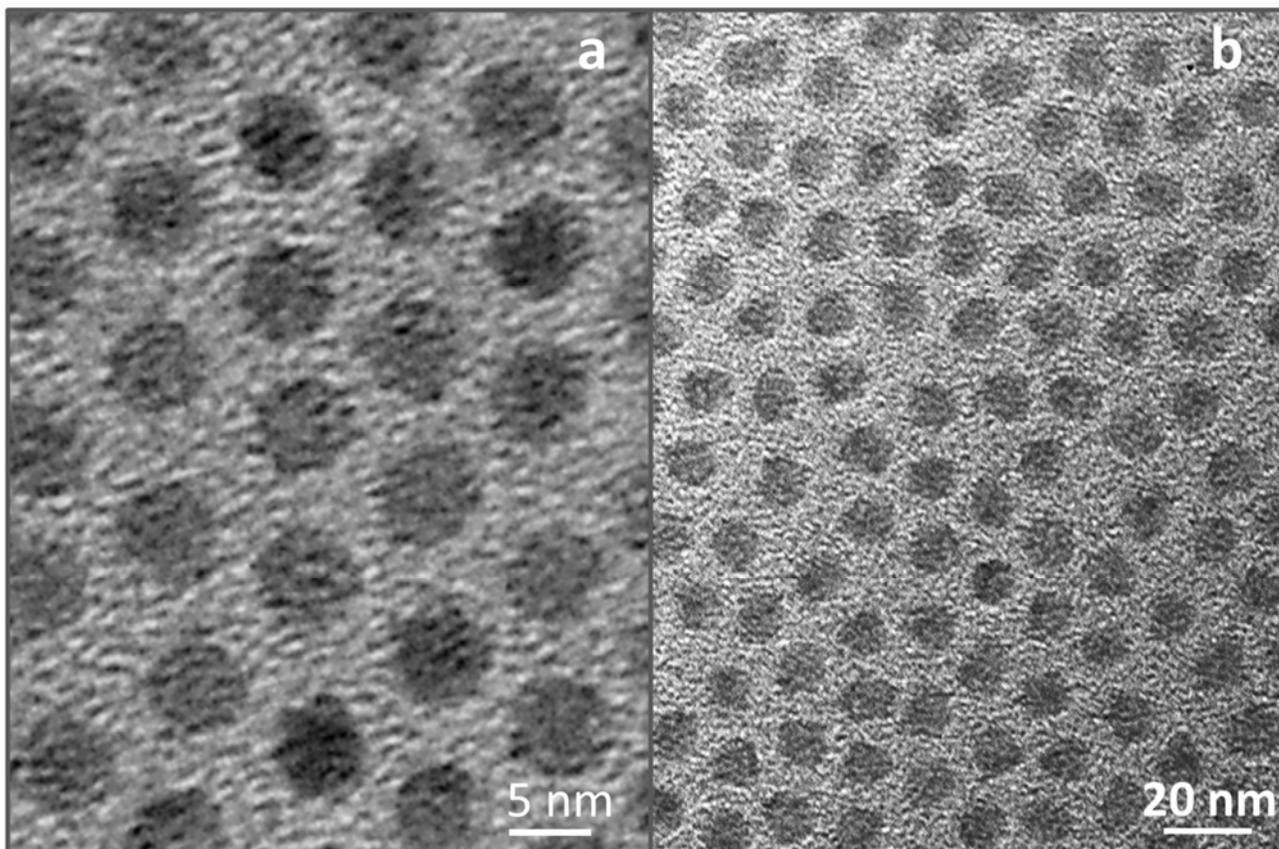
in the toluene phase. The minimal concentration of OLAM (for stabilizing nanocrystals in the non-polar phase) is indicated for each measurement.



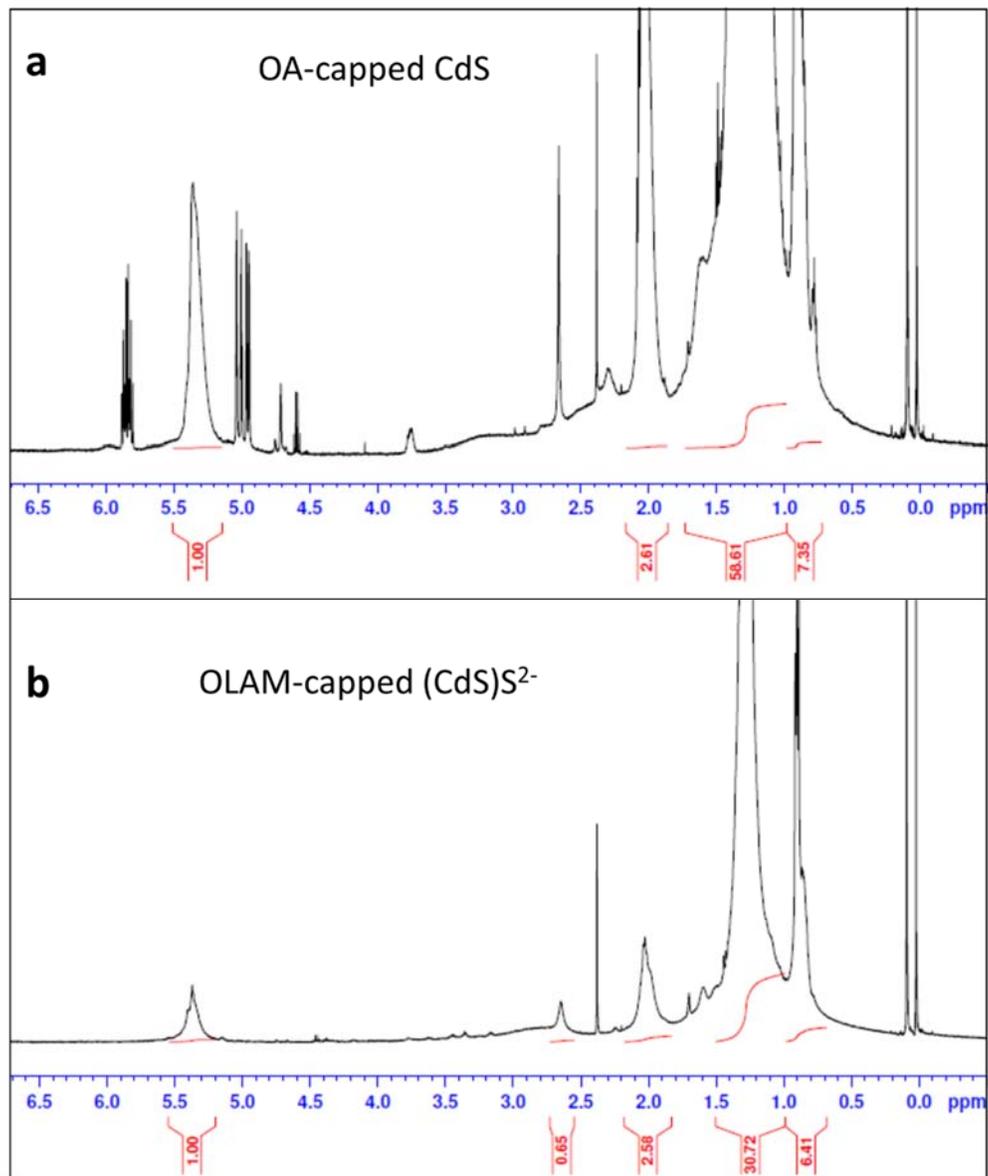
**Figure SF3.** FTIR spectra of the OLAM-capped (CdS) $S^{2-}$  NCs (black curve) and pure OLAM (red curve). The absence of the  $NH_2$  stretch modes tells us that OLAM attaches to the surface of nanoparticles by forming a complex with the sulfur ion.



**Figure SF4.** Evolution of the CdS<sub>318nm</sub> cluster absorption profile upon reacting with increasing amount of Cd(OAc)<sub>2</sub> ions in solution. The position of the exciton peak does not red-shift indicating that the surface of the CdS<sub>318</sub> cluster is likely to be saturated with Cd.



**Figure SF5.** Additional TEM images of CdS NCs grown by SILA technique. (a). CdS<sub>390nm</sub>+4(CdS<sub>1</sub>) NCs grown to a full layer saturation (b). CdS<sub>390nm</sub>+10(CdS<sub>1</sub>) NCs grown *without* full layer saturation.



**Figure SF6.** <sup>1</sup>H NMR spectra of (a). OA-capped CdS and (b). OLAM-capped (CdS)S<sup>2-</sup> NCs after the deposition of a sulfur layer.